

AUIPS7145R

CURRENT SENSE HIGH SIDE SWITCH

Features

- Suitable for 24V systems
- Over current shutdown
- Over temperature shutdown
- Current sensing
- Active clamp
- Reverse circulation immunization
- Low current
- ESD protection
- Optimized Turn On/Off for EMI

Applications

- 21W Filament lamp
- Solenoid
- 24V loads for trucks

Description

The AUIPS7145R is a fully protected four terminal high side switch specifically designed for driving lamp. It features current sensing, over-current, over-temperature, ESD protection and drain to source active clamp. The Ifb pin is used for current sensing. The over-current shutdown is higher than inrush current of the lamp.

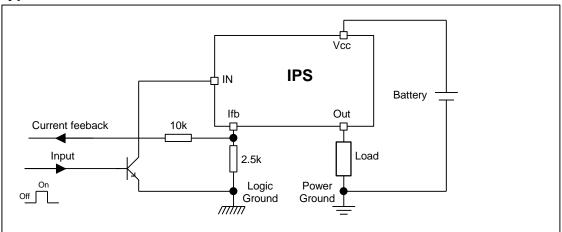
Product Summary

 $\begin{array}{ll} Rds(on) & 100m\Omega \ max. \\ Vclamp & 65V \\ Current \ shutdown & 20A \ min. \\ \end{array}$

Packages



Typical Connection





Qualification Information[†]

	oation information				
Qualification Level		Automotive (per AEC-Q100 ^{††})			
		Comments: This family of ICs has passed an Automotive qualification. IR's Industrial and Consumer qualification level is granted by extension of the higher Automotive level.			
Moisture Sensitivity Level		DPAK-5L	MSL1, 260°C (per IPC/JEDEC J-STD-020)		
	Machine Model		Class M2 (200 V) (per AEC-Q100-003)		
ESD	Human Body Model		ss H1C (1500 V) AEC-Q100-002)		
	Charged Device Model		ss C5 (1000 V) AEC-Q100-011)		
IC Latch	-Up Test		Class II, Level A (per AEC-Q100-004)		
RoHS Compliant		Yes			

Qualification standards can be found at International Rectifier's web site http://www.irf.com/ Exceptions to AEC-Q100 requirements are noted in the qualification report. †

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Absolute Maximum RatingsAbsolute maximum ratings indicate sustained limits beyond which damage to the device may occur. (Tj= -40°C..150°C,

Vcc=6..50V unless otherwise specified).

Symbol	Parameter	Min.	Max.	Units
Vout	Maximum output voltage	Vcc-60	Vcc+0.3	V
I rev	Maximum reverse pulsed current (t=100µs) see page 8	_	30	Α
Isd cont.	Maximum diode continuous current Tambient=25°C, Rth=70°C/W	_	2.3	A
Vcc-Vin max.	Maximum Vcc voltage	-16	60	V
lifb, max.	Maximum feedback current	-50	10	mΑ
Vcc sc.	Maximum Vcc voltage with short circuit protection see page 8	_	50	V
Pd	Maximum power dissipation (internally limited by thermal protection)			W
Fu	Rth=50°C/W DPack 6cm² footprint		2.5	VV
Ti may	Maximum operating junction temperature	-40	150	°C
Tj max.	Maximum storage junction temperature	-55	150	C

Thermal Characteristics

Symbol	Parameter	Тур.	Max.	Units
Rth1	Thermal resistance junction to ambient DPak Std footprint	70	_	
Rth2	Thermal resistance junction to ambient Dpak 6cm² footprint	50	_	°C/W
Rth3	Thermal resistance junction to case Dpak	4		Į.

Recommended Operating Conditions These values are given for a quick design.

Symbol	Parameter	Min.	Max.	Units
lout	Continuous output current, Tambient=85°C, Tj=125°C			۸
	Rth=50°C/W, Dpak 6cm² footprint	_	2.1	_ A
Rlfb	Ifb resistor	1.5	_	kΩ



Static Electrical Characteristics

Tj=-40°C..150°C, Vcc=6-50V (unless otherwise specified)

Symbol	Parameter	Min.	Тур.	Max.	Units	Test Conditions
Vcc op.	Operating voltage	6	_	60	V	
Rds(on)	ON state resistance Tj=25°C	_	75	100	mΩ	lds=2A
	ON state resistance Tj=150°C(2)	_	135	180	1115.2	IUS=ZA
Icc off	Supply leakage current	_	1	3		Vin=Vcc / Vifb=Vgnd
lout off	Output leakage current	_	1	3	μA	Vout=Vgnd, Tj=25°C
I in on	Input current while on	0.6	2	4	mA	Vcc-Vin=28V, Tj=25°C
V clamp1	Vcc to Vout clamp voltage 1	60	64	_		Id=10mA
V clamp2	Vcc to Vout clamp voltage 2	60	65	72		Id=6A see fig. 2
Vih(1)	High level Input threshold voltage	_	3	5	V	Id=10mA
Vil(1)	Low level Input threshold voltage	1.5	2.3	4.7	V	
Vf	Forward body diode voltage Tj=25°C	_	0.8	0.9		If=1A
	Forward body diode voltage Tj=125°C	_	0.65	0.75		

⁽¹⁾ Input thresholds are measured directly between the input pin and the tab.

Switching Electrical Characteristics Vcc=28V, Resistive load=27Ω, Tj=25°C

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Symbol	Parameter	Min.	Тур.	Max.	Units	Test Conditions	
tdon	Turn on delay time to 20%	4	10	20	0		
tr	Rise time from 20% to 80% of Vcc	2	5	10	μs	See fig. 1	
tdoff	Turn off delay time	20	40	80		See lig. 1	
tf	Fall time from 80% to 20% of Vcc	2.5	5	10	μs		

Protection Characteristics

Ti--40°C 150°C \/cc-6-50\/ (unless otherwise specified)

Symbol	Parameter	Min.	Тур.	Max.	Units	Test Conditions
Tsd	Over temperature threshold	150(2)	165	_	°C	See fig. 3 and fig.11
Isd	Over-current shutdown	20	25	35	Α	See fig. 3 and page 7
I fault	Ifb after an over-current or an over-temperature (latched)	2.2	3	5	mA	See fig. 3

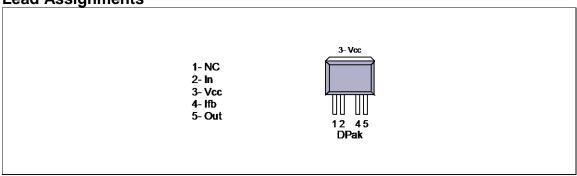
Current Sensing Characteristics

Ti=-40°C..150°C. Vcc=6-50V (unless otherwise specified). Specified 500us after the turn on. Vcc-Vifb>4V

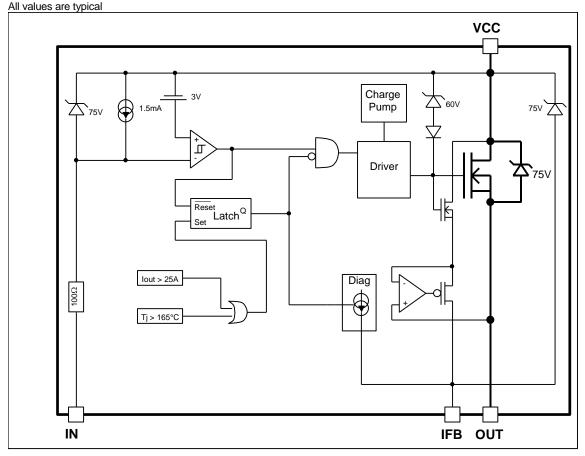
Symbol	Parameter	Min.	Тур.	Max.	Units	Test Conditions
Ratio	I load / Ifb current ratio	2000	2400	2800		lout<4A
Ratio_TC	I load / Ifb variation over temperature(2)	-5%	0	+5	%	Tj=-40°C to +150°C
I offset	Load current offset	-0.02	0	0.02	Α	lout<4A
Ifb leakage	Ifb leakage current On in open load	0	1	10	μA	Iout=0A, Vcc-Vin=28V

⁽²⁾ Guaranteed by design

Lead Assignments



Functional Block Diagram All values are typical



Truth Table

Op. Conditions	Input	Output	Ifb pin voltage
Normal mode	Н	L	0V
Normal mode	L	Н	I load x Rfb / Ratio
Open load	Н	L	0V
Open load	L	Н	0V
Short circuit to GND	Н	L	0V
Short circuit to GND	L	L	V fault (latched)
Over temperature	Н	L	0V
Over temperature	L	L	V fault (latched)

Operating voltage

Maximum Vcc voltage: this is the maximum voltage before the breakdown of the IC process.

Operating voltage: This is the Vcc range in which the functionality of the part is guaranteed. The AEC-Q100 qualification is run at the maximum operating voltage specified in the datasheet.

Reverse battery

During the reverse battery the Mosfet is kept off and the load current is flowing into the body diode of the power Mosfet. Power dissipation in the IPS: $P = I \log d * Vf$

There is no protection, so Tj must be lower than 150°C in the worst case condition of current and ambient temperature.

If the power dissipation is too high in Rifb, a diode in serial can be added to block the current.

The transistor used to pull-down the input should be a bipolar in order to block the reverse current. The 100ohm input resistor can not sustain continuously 16V (see Vcc-Vin max. in the Absolute Maximum Ratings section)

Active clamp

The purpose of the active clamp is to limit the voltage across the MOSFET to a value below the body diode break down voltage to reduce the amount of stress on the device during switching.

The temperature increase during active clamp can be estimated as follows:

$$\Delta_{\mathsf{Tj}} = P_{\mathsf{CL}} \cdot Z_{\mathsf{TH}}(t_{\mathsf{CLAMP}})$$

Where: $Z_{TH}(t_{CLAMP})$ is the thermal impedance at t_{CLAMP} and can be read from the thermal impedance curves given in the data sheets.

 $\mathbf{P}_{\mathrm{CL}} \equiv \mathbf{V}_{\mathrm{CL}} \cdot \mathbf{I}_{\mathrm{CLavq}}$: Power dissipation during active clamp

 $V_{CL} = 65V$: Typical V_{CLAMP} value.

 $I_{\text{CLavg}} = \frac{I_{\text{CL}}}{2} : \text{Average current during active clamp}$

 $t_{CL} = \frac{I_{CL}}{\left| \frac{di}{t} \right|}$: Active clamp duration

 $\frac{di}{dt} = \frac{V_{\text{Battery}} - V_{\text{CL}}}{L} : \text{Demagnetization current}$

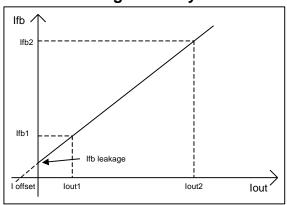
Figure 9 gives the maximum inductance versus the load current in the worst case : the part switches off after an over temperature detection. If the load inductance exceeds the curve, a free wheeling diode is required.



Over-current protection

The threshold of the over-current protection is set in order to guarantee that the device is able to turn on a load with an inrush current lower than the minimum of lsd. Nevertheless for high current and high temperature the device may switch off for a lower current due to the over-temperature protection. This behavior is shown in Figure 11.

Current sensing accuracy



The current sensing is specified by measuring 3 points :

- Ifb1 for lout1
- Ifb2 for lout2
- Ifb leakage for lout=0

The parameters in the datasheet are computed with the following formula:

Ratio = (lout2 - lout1)/(lfb2 - lfb1)

I offset = Ifb1 x Ratio - Iout1

This allows the designer to evaluate the Ifb for any lout value using:

Ifb = (lout + I offset) / Ratio if Ifb > Ifb leakage

For some applications, a calibration is required. In that case, the accuracy of the system will depends on the variation of the I offset and the ratio over the temperature range. The ratio variation is given by Ratio_TC specified in page 4.

The loffset variation depends directly on the Rdson:

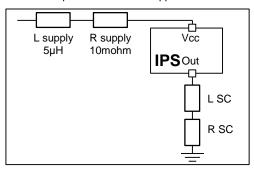
I offset@-40°C= I offset@25°C / 0.8

I offset@150°C= I offset@25°C / 1.9



Maximum Vcc voltage with short circuit protection

The maximum Vcc voltage with short circuit is the maximum voltage for which the part is able to protect itself under test conditions representative of the application. 2 kind of short circuits are considered: terminal and load short circuit.



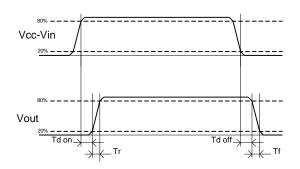
	L SC	R SC
Terminal SC	0.1 μΗ	10 mohm
Load SC	10 μH	100 mohm

Maximum current during reverse circulation

In case of short circuit to battery, a voltage drop of the Vcc may create a current which circulate in reverse mode. When the device is on, this reverse circulation current will not trigger the internal fault latch. This immunization is also true when the part turns on while a reverse current flows into the device. The maximum current (I rev) is specified in the maximum rating section.

AUIPS7145R





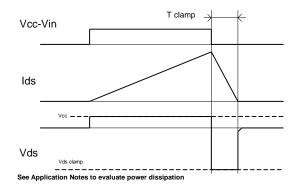


Figure 1 - IN rise time & switching definitions

Vin Ishutdown

Ti Tsd 165°C

Vifb V fault

Figure 3 – Protection timing diagram

Figure 2 - Active clamp waveforms

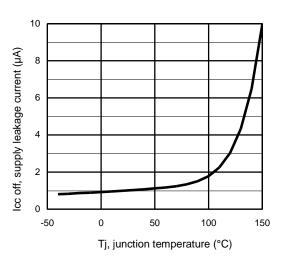


Figure 4 – Icc off (µA) Vs Tj (°C)

150

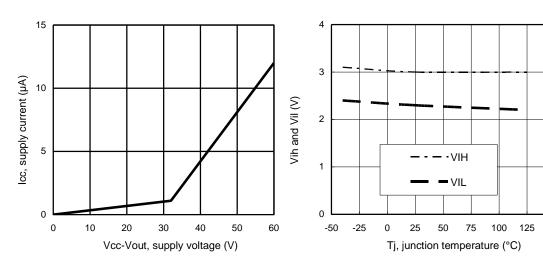
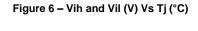


Figure 5 – Icc off (µA) Vs Vcc-Vout (V)



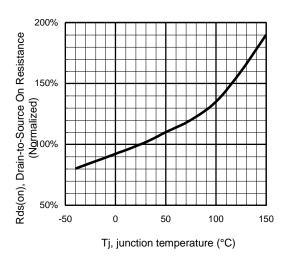


Figure 7 - Normalized Rds(on) (%) Vs Tj (°C)

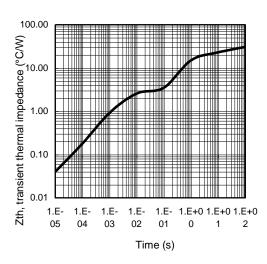
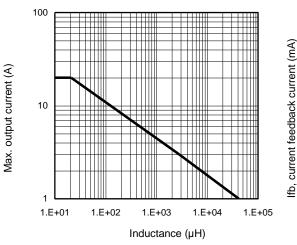


Figure 8 – Transient thermal impedance (°C/W)
Vs time (s)



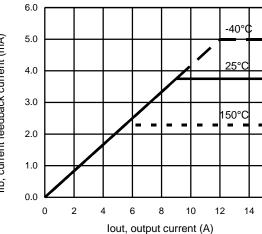


Figure 9 - Max. lout (A) Vs inductance (µH)

Figure 10 - Ifb (mA) Vs lout (A)

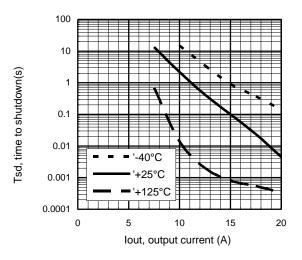
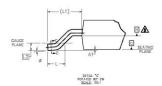
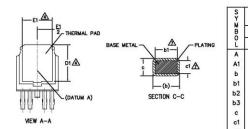
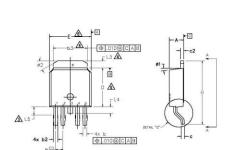


Figure 11 – Tsd (s) Vs I out (A) SMD with 6cm²

Case Outline 5 Lead - DPAK





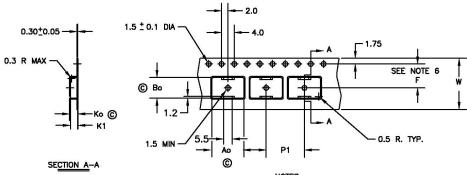


Y		DIMEN	ISIONS		N
Y M B O	MILLIM	ETERS	INC	HES	O
Ĉ.	MIN.	MAX.	MIN.	MAX.	Ė
Α	2.18	2.39	.086	.094	
A1	_	0.13	-	.005	
b	0.56	0.79	.022	.031	
b 1	.056	0.74	.022	.029	2
b2	0.65	0.89	.026	.035	1117.5
b3	4.95	5.46	.195	.215	2
c	0.46	0.61	.018	.024	
c1	0.41	0.56	.016	.022	2
c2	0.46	0.89	.018	.035	
D	5.97	6.22	.235	.245	3
D1	5.21	-	.205	-	
Ε	6.35	6.73	.250	.265	3
E1	4.32	-	.170	-	
e	1.14	1.14 BSC		BSC	
н	9.40	10.41	.370	.410	
L	1.40	1.78	.055	.070	
L1	2.74	BSC	.108	REF.	
L2	0.51	BSC	.020	BSC	
L3	0.89	1.27	.035	.050	
L4	-	1.02	-	.040	
L5	1.14	1.52	.045	.060	
ø	0.	10*	0.	10*	
ø1	0.	15*	0.	15*	
ø2	28*	32*	28*	32*	

NOTES:

- 1.- DIMENSIONING AND TOLERANCING AS PER ASME Y14.5M-1994
- 2.- DIMENSION ARE SHOWN IN INCHES [MILLIMETERS].
- LEAD DIMENSION UNCONTROLLED IN L5.
- A- DIMENSION D1, E1, L3 & b3 ESTABLISH A MINIMUM MOUNTING SURFACE FOR THERMAL PAD.
- 5.— SECTION C-C DIMENSIONS APPLY TO THE FLAT SECTION OF THE LEAD BETWEEN .005 AND 0.10 [0.13 AND 0.25] FROM THE LEAD TIP.
- DIMENSION D & E DO NOT INCLUDE MOLD FLASH, MOLD FLASH SHALL NOT EXCEED .005 [0.13] PER SIDE. THESE DIMENSIONS ARE MEASURED AT THE OUTMOST EXTREMES OF THE PLASTIC BODY.
- A- DIMENSION b1 & c1 APPLIED TO BASE METAL ONLY.
- 8.- DATUM A & B TO BE DETERMINED AT DATUM PLANE H.
- 9.- OUTLINE CONFORMS TO JEDEC OUTLINE TO-252.
- 10. LEADS AND DRAIN ARE PLATED WITH 100% Sn

Tape & Reel 5 Lead - DPAK



Ao = 10.5 mm Bo = 7.0 mm Ko = 2.8 mm K1 = 2.4 mm F = 7.5 mm P1 = 12.0 mm 16.0 ± .3 mm

NOTES:

- 2. 3. 4.
- 10 SPROCKET HOLE PUNCH CUMULATIVE TOLERANCE ±.02
 CAMBER NOT TO EXCEED 1mm IN 100mm
 MATERIAL: CONDUCTIVE BLACK POLYSTYRENE
 AC AND BO MEASURED ON A PLANE 0.3mm ABOVE THE
 BOTTOM OF THE POCKET
 KO MEASURED FROM A PLANE ON THE INSIDE BOTTOM OF THE
 POCKET TO THE TOP SURFACE OF THE CARRIER
 POCKET POSITION RELATIVE TO THE SPROCKET HOLE MEASURED AS
 TRUE POSITION OF POCKET, NOT POCKET HOLE

- TRUE POSITION OF POCKET, NOT POCKET HOLE

 7. VENDOR: (OPTIONAL)

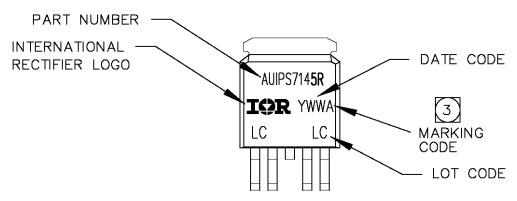
 8. MUST ALSO MEET REQUIREMENTS OF EIA STANDARD #EIA-481A,
 TAPING OF SURFACE-MOUNT COMPONENTS FOR AUTOMATIC
 PLACEMENT.

 9. TOLERANCE TO BE MANUFACTURER STANDARD

 10. SURFACE RESISTIVITY OF MOLDED MATL: MUST MEASURE
 LESS THAN OR EQUAL TO 10* OHMS PER SQUARE. MEASURED
 IN ACCORDANCE TO PROCEDURE GIVEN IN ASTM D-257 &
 ASTM D-991 (REF. C-9000 SPEC.)

 11. TOTAL LENGTH PER REEL MUST BE 79 METERS
- 12. C CRITICAL DIMENSION

Part Marking Information



Ordering Information

Base Part Number		Standard Pack	0 14 5 44 1	
base i ait i dilibei	Package Type	Form	Quantity	Complete Part Number
	D-Pak-5-Lead	Tube	75	AUIPS7145R
ALUDO714ED		Tape and reel	2000	AUIPS7145RTR
AUIPS7145R		Tape and reel left	3000	AUIPS7145RTRL
		Tape and reel right	3000	AUIPS7145RTRR



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For technical support, please contact IR's Technical Assistance Center http://www.irf.com/technical-info/

WORLD HEADQUARTERS:

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Revision History

A1 12/11/2009 First release A2 10/03/2010 Add tri-temp	
A2 10/03/2010 Add tri-temp	
A3 20/04/2010 DR3 release	
B 26/08/2011 Add Vil max page 4	4
C 10/02/2012 Update storage tem	nperature page 3

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